

Substitute Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 07977-227002	Application No. 09/621,943
<b>Information Disclosure Statement by Applicant</b> (Use several sheets if necessary)  (37 CFR §1.98(b))		Applicant Hisashi Ohtani	
		Filing Date July 24, 2000	Group Art Unit 2822

## U.S. Patent Documents

Examiner Initial	Desig. ID	Patent Number	Issue Date	Patentee	Class	Subclass	Filing Date If Appropriate
O I P E AUG 28 2002 PATENT & TRADEMARK OFFICE	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

## Foreign Patent Documents or Published Foreign Patent Applications

Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AL							
	AM							
	AN							
	AO							
	AP							

## Other Documents (include Author, Title, Date, and Place of Publication)

Examiner Initial	Desig. ID	Document
J.B.	AQ	King, et al, "Polycrystalline Silicon-Germanium Thin-Film Transistors," September, 1994, Stanford, CA
	AR	
	AS	
	AT	

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Examiner Signature <i>James L. Brophy</i>	Date Considered NOV. 12, 2002
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